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Absolute Maximum Ratings(Note 1)

Absolute Maximum Ratings(Note 1)		Recommended Operating		
Supply Voltage (V _{CC})	-0.5V to +4.6V	Conditions (Note 3)		
DC Input Voltage (VI)	-0.5V to +4.6V	Power Supply		
Output Voltage (V _O) (Note 2)	-0.5V to +4.6V	Operating	1.65V to 3.6V	
DC Input Diode Current (IIK)		Data Retention Only	1.2V to 3.6V	
V ₁ < 0V	-50 mA	Input Voltage	-0.3V to 3.6V	
DC Output Diode Current (I _{OK})		Output Voltage (V _O)	0V to V _{CC}	
V _O < 0V	-50 mA	Output Current in I _{OL}		
DC Output Source/Sink Current (I _{OL})	+50 mA	$V_{CC} = 3.0V$ to 3.6V	±24 mA	
DC V _{CC} or Ground Current per	±100 mA	$V_{CC} = 2.3V$ to 2.7V	±18 mA	
Supply Pin (I _{CC} or Ground)		$V_{CC} = 1.65V$ to 2.3V	±6 mA	
Storage Temperature Range (T _{stg})	$-65^{\circ}C$ to $+150^{\circ}C$	Free Air Operating Temperature (T _A)	$-40^\circ C$ to $+85^\circ C$	
		Minimum Input Edge Rate ($\Delta t/\Delta V$)		

 V_{in} = 0.8V to 2.0V, V_{CC} = 3.0V 10 ns/V

Not 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Rat-ings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW

DC Electrical Characteristics (2.7V $< V_{CC} \leq 3.6V)$

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
VIH	HIGH Level Input Voltage		2.7–3.6	2.0		V
V _{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7–3.6		0.2	
		I _{OL} = 12 mA	2.7		0.4	v
		I _{OL} = 18 mA	3.0		0.4	v
		I _{OL} = 24 mA	3.0		0.55	
I _I	Input Leakage Current	$0 \le V_I \le 3.6V$	2.7–3.6		±5.0	μΑ
I _{OFF}	Power-Off Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μΑ
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7–3.6		20	
		$V_{CC} \le V_I \le 3.6V$	2.7–3.6		±20	μA
∆l _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7–3.6		750	μΑ

DC Electrical Characteristics	$(2.3V \le V_{CC} \le 2.7V)$
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74VCX38 Vcc Min Units Symbol Conditions Max Parameter (V) VIH HIGH Level Input Voltage 2.3-2.7 1.6 V VIL LOW Level Input Voltage 2.3-2.7 0.8 V LOW Level Output Voltage 2.3-2.7 V_{OL} $I_{OL} = 100 \ \mu A$ 0.2 v $I_{OL} = 12 \text{ mA}$ 2.3 0.4 I_{OL} = 18 mA 2.3 0.6 Input Leakage Current $0 \leq V_I \leq 3.6V$ 2.3-2.7 ±5.0 μΑ Power-Off Leakage Current $0 \leq (V_I, \ V_O) \leq 3.6 V$ 0 10 μΑ IOFF Quiescent Supply Current $V_I = V_{CC}$ or GND 20 2.3-2.7 I_{CC} μA $V_{CC} \leq V_I \leq 3.6V$ 2.3–2.7 ±20

DC Electrical Characteristics (1.65V \leq V_{CC} < 2.3V)

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 x V _{CC}		V
VIL	LOW Level Input Voltage		1.65–2.3		$0.35 \times \mathrm{V_{CC}}$	V
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	1.65–2.3		0.2	V
		$I_{OL} = 6 \text{ mA}$	1.65		0.3	v
I _I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65–2.3		±5.0	μA
I _{OFF}	Power-Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65–2.3		20	μA
		$V_{CC} \le V_I \le 3.6 V$	1.65–2.3		±20	

AC Electrical Characteristics (Note 4)

			$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $C_L = 30$ pF, $R_L = 500\Omega$					
Symbol	Parameter	$V_{CC} = 3$	$V_{CC}=3.3V\pm\!0.3V$		$V_{CC}=2.5V\pm\!0.2V$		$V_{CC}=1.8V \pm 0.15V$	
		Min	Max	Min	Max	Min	Max	
t _{PZL}	Propagation Delay	0.6	2.8	0.8	3.7	1.0	6.7	ns
t _{PLZ}								
t _{OSHL}	Output to Output Skew (Note 5)		0.5		0.5		0.75	ns
t _{OSLH}								

Note 4: For C₁ = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

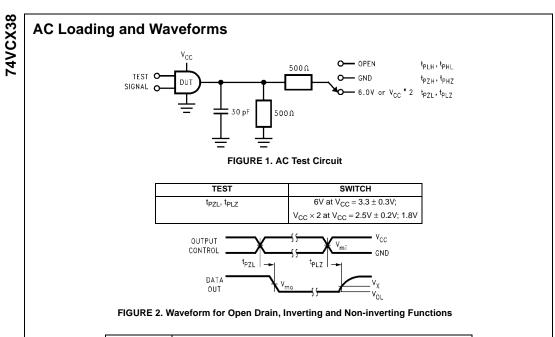
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = +25°C Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.25	
			2.5	-0.6	V
			3.3	-0.8	

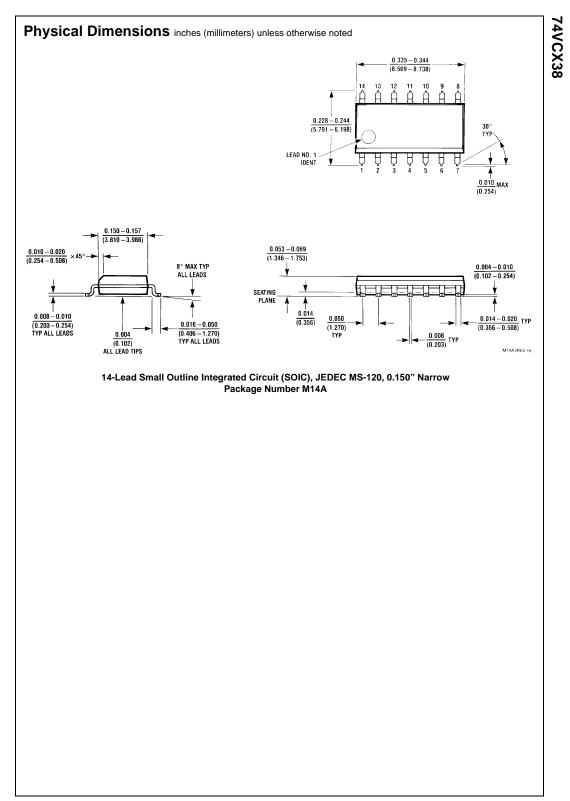
Capacitance

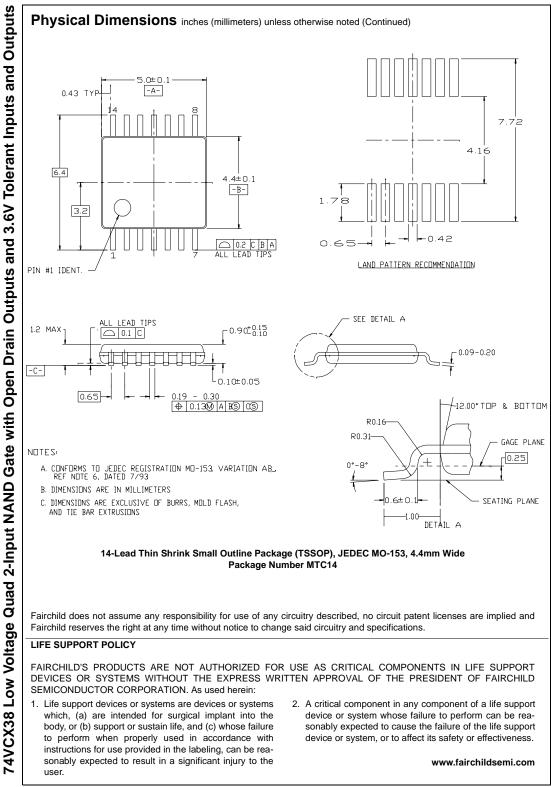
Symbol	Parameter	Conditions	T _A +25°C	Units
	Falanetei	Conditions	Typical	Units
CIN	Input Capacitance	$V_{I} = 0v \text{ OR } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	6	pF
C _{OUT}	Output Capacitance	$V_I = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	7	pF
C _{PD}	Power Dissipation Capacitance	V_{I} = 0V or V_{CC},f = 10 MHz, V_{CC} = 1.8V, 2.5V or 3.3V	20	pF

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Symbol		v _{cc}	
Gymbol	$\textbf{3.3V}\pm\textbf{0.3V}$	$\textbf{2.5V} \pm \textbf{0.2V}$	$\textbf{1.8V} \pm \textbf{0.15V}$
V _{mi}	1.5V	V _{CC} /2	V _{CC} /2
V _{mo}	1.5V	V _{CC} /2	V _{CC} /2
V _x	V _{OL} + 0.3V	V _{OL} + 0.15V	V _{OL} + 0.15V





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